## NSN 5961-01-212-8006

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-212-8006 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage **Current Rating Per Characteristic:** 8.00 amperes drain current **Power Rating Per Characteristic:** 25.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 78711-t235a372 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No